# University of Swaziland Faculty of Science and Engineering Department of Electrical and Electronic Engineering

## Main Examination 2017

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Title of pape	r: Analo	gue Desig	gn I / A	nalogue J	Electronics	1 I

Course Number: EEE321 / EE321

Time allowed: 3 hours

## **Instructions:**

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- 1. EE321 students answer any FOUR (4) questions in section A
- 2. EEE321 students answer any THREE (3) questions in section A and ONE (1) question in section B
- 3. Each question carries 25 marks
- 4. Marks for each question are shown at the right hand margin

This paper contains 7 pages including this one.

This paper should not be opened until permission has been granted by the invigilator.

#### Section A

#### Question 1

- a) State the three modes of operation of an NPN transistor and tabulate the bias conditions of the junctions.
- b) For the circuit **Figure 1** below determine the node currents  $I_C$ ,  $I_B$  and  $I_E$  and determine the mode of operation of the transistor for  $\beta = 100$ . [8]
- c) Draw the voltage transfer characteristics of a BJT and explain how the output signal is affected by the location of quiescent point (Q-point). [5]
- d) Describe how to find the current  $i_D$  of a MOSFET in terms of the charge Q per unit length and the electron drift velocity. Assume a small  $v_{DS}$  is applied to the transistor. [6]



#### Figure 1

#### **Question 2**

In the circuit Figure 2,  $v_{sig}$  is a small sine wave signal with zero average. The transistor  $\beta$  is 100,  $V_{BE} = 0.7V$ ,  $V_T = 25mV$ ,  $I_C = 0.5mA$ ,  $R_C = 20k\Omega$ .  $R_L = 10k\Omega$  and  $r_0 = 200k\Omega$ .



Figure 2

a)	Draw the small signal equivalent circuit of the amplifier.	[3]
b)	Determine the overall voltage gain, $\frac{v_0}{v_{sig}}$ .	[10]

c) For a 0.08  $\mu m$  process technology for which  $t_{ox} = 15nm$  and  $\mu_n = 550cm^2/V.s$ . Given that the transistor is operating in saturation with  $I_D = 0.2mA$  with  $\frac{W}{L} = 20$ , Find

i)	$C_{ox}$	[2]
ii)	$k'_n$	[3]
iii)	Vov	* [4]

d) An op-amp has a slew rate of  $10V/\mu S$ , full-power bandwidth,  $\omega_M = 2 \times 10^6 \ rad/sec$ What is the rated output voltage,  $v_{0max}$ ? [3]

## **Question 3**

Consider the Common-source amplifier circuit, Figure 3(a) below.

- a) Draw the small signal equivalent circuit. [3]
  b) Find
  - i) The input resistance  $R_{in}$  [2]



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Figure 3 (a)

- c) Given the circuit shown in Figure 3 (b) below,  $R_1 = 100k\Omega$ ,  $R_2 = 50 k\Omega$ ,  $R_c = 5k\Omega$ ,  $R_E = 3k\Omega$ ,  $\beta = 100$ ,  $V_{BE} = 0.7V$ 
  - i) Calculate the following DC parameters  $V_{BB}$ ,  $I_B$ ,  $I_E$ ,  $I_C$ ,  $V_C$ . [10]
  - ii) Draw the resultant circuit, and label all the parameters correctly. [3]



Figure 3 (b)

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## Question 4

a) A BJT operating at  $I_c = 2mA$  has  $C_{\mu} = 1pF C_{\pi} = 10pF$  and  $\beta = 150$ . Calculate:

	i) $f_T$	·	[4]
	ii) $f_{\beta}$	2	[4]
b)	For the op	p-amp inverting integrator circuit,	
	i) Dr	raw and label the circuit diagram.	[3]
	ii) De	etermine the voltage across the capacitor.	[4]
	iii) De	etermine output voltage.	[2]

c) Using an ideal op-amp, design the inverting low-pass amplifier circuit shown in Figure 4 having a pole frequency of 3kHz
 [8]



Figure 4

## Question 5

Consider the common-emitter amplifier shown in **Figure 5** under the following conditions:  $R_{sig} = 5k\Omega$ ,  $R_1 = 33k\Omega$ ,  $R_2 = 22k\Omega$ ,  $R_E = 3.9k\Omega$ ,  $R_C = 4.7k\Omega$ ,  $R_L = 5.6k\Omega$ ,  $V_{CC} = 5V$ ,  $r_0 = 300k\Omega$ ,  $\beta = 120$ , dc collector current,  $I_C = 0.3mA$ ,  $V_T = 25mV$ ,  $C_{\mu} = 1 pF$ ,  $f_T = 700MHz$ ,  $r_x = 50\Omega$ , Find

a) 
$$C_{\pi}$$
 [7]  
b) The under 2dD for even  $f$  [7]

b) The upper-3dB frequency 
$$f_H$$
 [18]





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# Section B

Question 6		
a) List and describe the four elements of a regulator circuit.		[8]
b) State three types of regulators		[3]
c) In the circuit <b>Figure 6</b> below	à	
i) Identify the type of regulator.	4°	[2]
ii) Identify the four elements listed above.		[4]
iii) Find the output voltage.		[3]



Figure 6

d) For a half-wave rectifier, show that the efficiency  $\eta = 0.405$ [5]

## **Question** 7

b)

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a)	State a regulator type of your choice and do the following	
	i) Draw the circuit diagram.	[3]
	ii) Describe the operation of the regulator.	[6]
	iii) Write the equations of the output voltage and the associate currents.	[4]
b)	For a rectifier of your choice	
	i) Draw the circuit diagram.	[3]
	ii) Find the RMS values of the load voltage and the load current.	[9]